



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of
Shunpei YAMAZAKI et al.

Serial No. 09/352,362

Filed: July 13, 1999

For: CRYSTALLINE SEMICONDUCTOR

THIN FILM, METHOD OF FABRICATING

THE SAME, SEMICONDUCTOR DEVICE,

AND METHOD OF FABRICATING THE

SAME

) Art Unit: 2815

) Examiner: J. Diaz

CERTIFICATE OF MAILING

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Andt
J Mcmillan
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RESPONSE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450
Sir:

In response to the Official Action dated January 30, 2003, please amend the
above-identified application as follows:

IN THE CLAIMS:

Please amend claims 16 and 19 as follows:

16. A method according to claim 15, wherein the second heat treatment is
carried out in the reducing atmosphere in which a concentration of oxygen or an oxide
compound is not higher than 10 ppm.

19. A method according to claim 17, wherein the second heat treatment is
carried out in the reducing atmosphere in which a concentration of oxygen or an oxide
compound is not higher than 10 ppm.

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